# 2SC4134

# ON Semiconductor®

http://onsemi.com

· High breakdown voltage and large current capacity

# **Bipolar Transistor**

100V, 1A, Low VCE(sat), NPN Single TP/TP-FA

#### **Applications**

• Power supplies, relay drivers, lamp drivers

#### **Features**

- · Adoption FBET, MBIT processes
- · Fast switching speed
- · Small and slim package permitting 2SC4134-applied sets to be made more compact

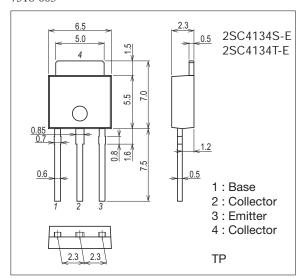
#### **Specifications**

Absolute Maximum Ratings at Ta=25°C

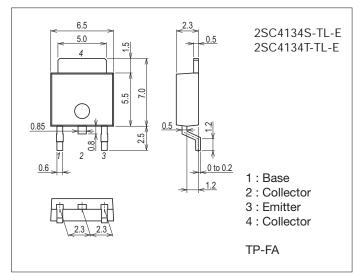
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		120	V
Collector-to-Emitter Voltage	VCEO		100	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		6	V
Collector Current	IC		1	Α
Collector Current (Pulse)	ICP		2	Α

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### Package Dimensions unit: mm (typ) 7518-003



## Package Dimensions unit : mm (typ) 7003-003



#### **Product & Package Information**

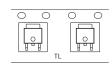
- $\bullet \ Package: TP$
- JEITA, JEDEC: SC-64, TO-251
- Minimum Packing Quantity : 500 pcs./bag

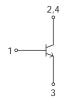
# Marking (TP, TP-FA)



- Package: TP-FA
- JEITA, JEDEC: SC-63, TO-252
- Minimum Packing Quantity: 700 pcs./reel

Packing Type (TP-FA): TL Electrical Connection





Semiconductor Components Industries, LLC, 2013

September, 2013

#### Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	Do.		0.8	W
Collector Dissipation	PC	Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

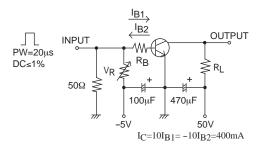
#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Symbol		min	typ	max	Offic	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =100V, I <sub>E</sub> =0A			100	nA	
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =4V, I <sub>C</sub> =0A			100	nA	
DC Current Gain	hFE	V <sub>CE</sub> =5V, I <sub>C</sub> =100mA	100*		400*		
Gain-Bandwidth Product	fT	V <sub>CE</sub> =10V, I <sub>C</sub> =100mA		120		MHz	
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		8.5		рF	
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =400mA, I <sub>B</sub> =40mA		0.1	0.4	V	
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> =400mA, I <sub>B</sub> =40mA		0.85	1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =10μA, I <sub>E</sub> =0A	120			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	100			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =10μA, I <sub>C</sub> =0A	6			V	
Turn-ON Time	ton			80		ns	
Storage Time	t <sub>stg</sub>	See specified Test Circuit.		850		ns	
Fall Time	tf			50		ns	

#### $^{\star}$ : The 2SC4134 is classified by 100mA $h_{\mbox{\scriptsize FE}}$ as follows :

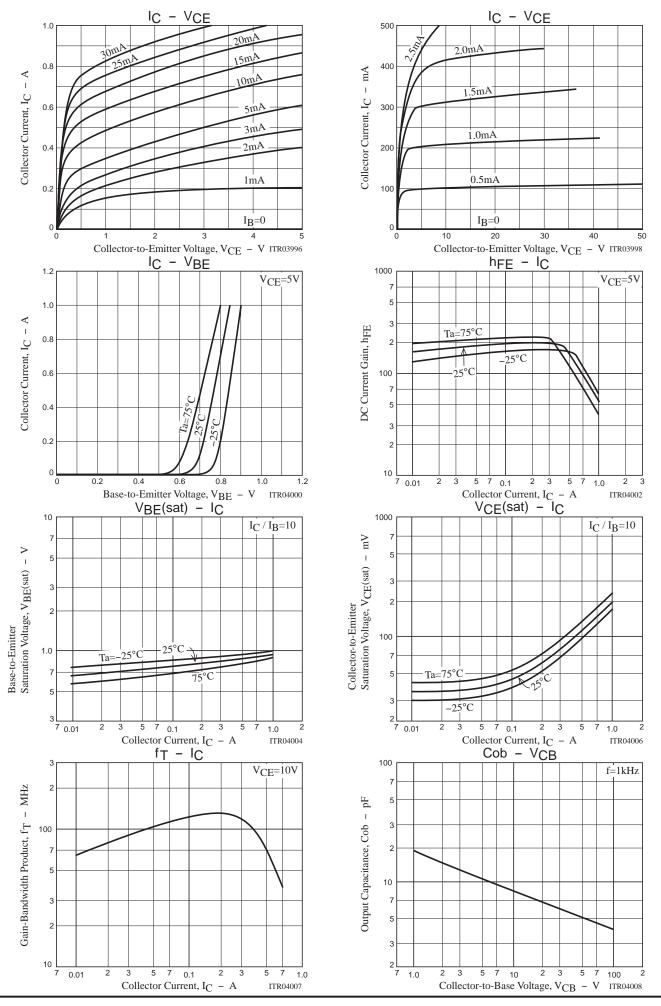
Rank	R	S	T	
hFE	100 to 200	140 to 280	200 to 400	

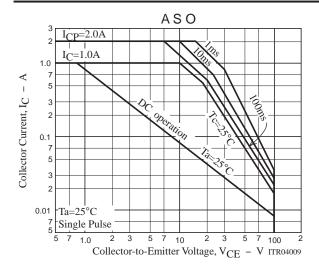
#### **Switching Time Test Circuit**

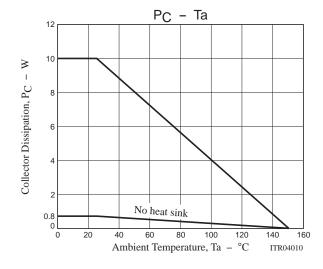


#### **Ordering Information**

G. a.cgc			
Device	Device Package Shipping		memo
2SC4134S-E	TP	500pcs./bag	
2SC4134T-E	TP	500pcs./bag	Pb Free
2SC4134S-TL-E	TP-FA	700pcs./reel	Pb Fiee
2SC4134T-TL-E	TP-FA	700pcs./reel	





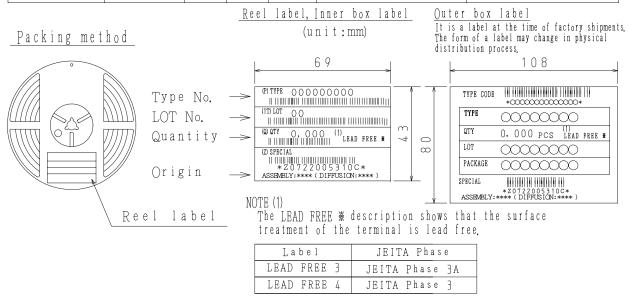


#### **Taping Specification**

#### 2SC4134S-TL-E, 2SC4134T-TL-E

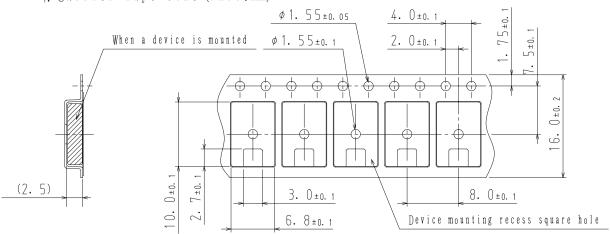
Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	format
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer $BOX(A-7)$
TP-FA	TP	700	2, 100	12,600	3 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210

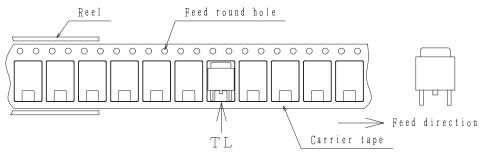


#### Taping configuration

1. Carrier tape size (unit:mm)



7. Device placement direction

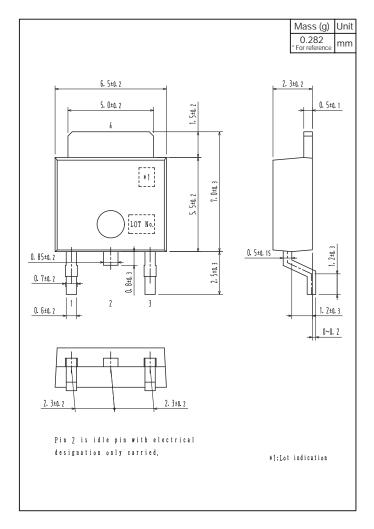


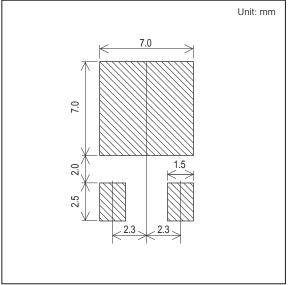
Those with one electrode terminal on the feed hole side · · · · · · TL

#### **Outline Drawing**

2SC4134S-TL-E, 2SC4134T-TL-E

#### **Land Pattern Example**





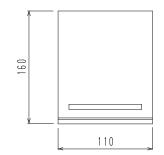
#### Bag Packing Specification

2SC4134S-E, 2SC4134T-E

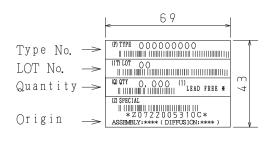
#### 1. Packing Format

Package Name		Maximum Number of devices contained (pcs)				
1 4 0 14 6 0 14 8 110	Вад	Inner box	Inner box Outer			
TP		B-1	A-1	A-2 30,000		
1 Γ	500	10,000	50,000			
		Packing format (Dimensions:mm (external))				
		Inner box	Outer	bох		
		B-1	A-1	A-2		
		445×225×55	470×250×300	470×250×190		

# 2. Bag dimensions (unit:mm)





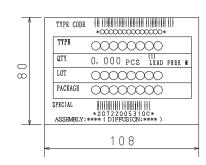


# 4. Outer box label (unit:mm)

It is a label at the time of factory shipments, The form of a label may change in physical distribution process,

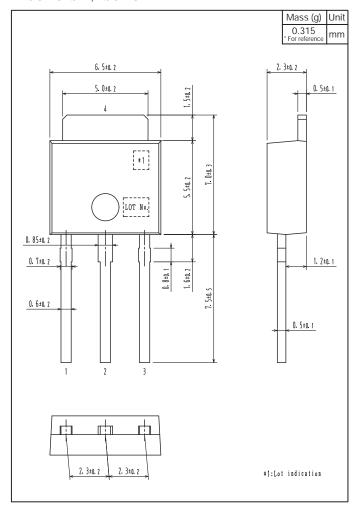
NOTE(1)
The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

Label			JEITA Phase
LEAD	FREE	3	JEITA Phase 3A
LEAD	FREE	4	JEITA Phase 3



#### **Outline Drawing**

2SC4134S-E, 2SC4134T-E



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